TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74VHCT74AF,TC74VHCT74AFN,TC74VHCT74AFT

Dual D-Type Flip-Flop with Preset and Clear

The TC74VHCT74 is an advanced high speed CMOS D-FLIP FLOP fabricated with silicon gate C^2MOS technology. It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

The signal level applied to the D INPUT is transferred to Q OUTPUT during the positive going transition of the CK pulse.

$\overline{CLR}$ and $\overline{PR}$ are independent of the CK and are accomplished by setting the appropriate input low.

The input voltage are compatible with TTL output voltage.

This device may be used as a level converter for interfacing 3.3 V to 5 V system.

Input protection and output circuit ensure that 0 to 5.5 V can be applied to the input and output (Note) pins without regard to the supply voltage. These structure prevents device destruction due to mismatched supply and input/output voltages such as battery back up, hot board insertion, etc.

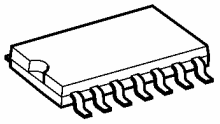
Note: V_{CC} = 0 V

Features

- High speed: f_{max} = 160 MHz (typ.) at V_{CC} = 5 V
- Low power dissipation: I_{CC} = 2 μA (max) at Ta = 25°C
- Compatible with TTL outputs: V_{IL} = 0.8 V (max)
  V_{IH} = 2.0 V (min)
- Power down protection is provided on all inputs and outputs
- Balanced propagation delays: $t_{pLH} \simeq t_{pHL}$
- Pin and function compatible with the 74 series (74AC/HC/F/ALS/LS etc.) 74 type.

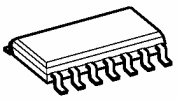
Note: The JEDEC SOP (FN) is not available in Japan.

TC74VHCT74AF



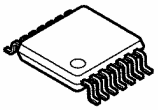
SOP14-P-300-1.27A

TC74VHCT74AFN



SOL14-P-150-1.27

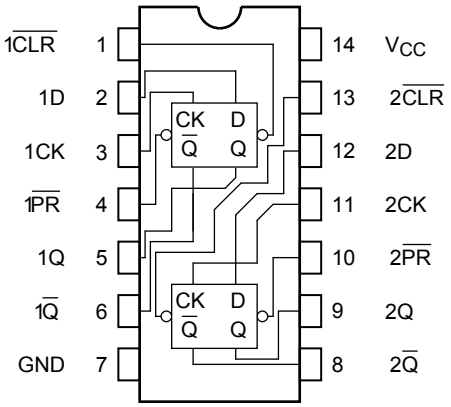
TC74VHCT74AFT



TSSOP14-P-0044-0.65A

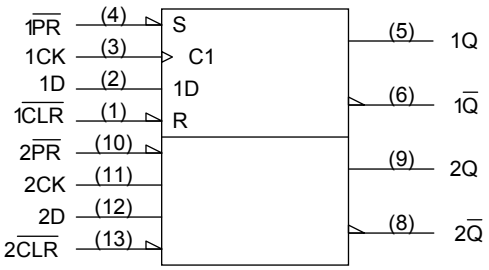
Weight
SOP14-P-300-1.27A : 0.18 g (typ.)
SOL14-P-150-1.27 : 0.12 g (typ.)
TSSOP14-P-0044-0.65A : 0.06 g (typ.)

Pin Assignment



(top view)

IEC Logic Symbol



Truth Table

Inputs				Outputs		Function
$\overline{CLR}$	$\overline{PR}$	D	CK	Q	$\overline{Q}$	
L	H	X	X	L	H	Clear
H	L	X	X	H	L	Preset
L	L	X	X	H	H	—
H	H	L	↑	L	H	—
H	H	H	↑	H	L	—
H	H	X	↓	Q_n	$\overline{Q}_n$	No Change

X: Don't care

Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating		Unit
Supply voltage range	V_{CC}	−0.5 to 7.0		V
DC input voltage	V_{IN}	−0.5 to 7.0		V
DC output voltage	V_{OUT}	−0.5 to 7.0	(Note 2)	V
		−0.5 to V_{CC} + 0.5	(Note 3)	
Input diode current	I_{IK}	−20		mA
Output diode current	I_{OK}	±20	(Note 4)	mA
DC output current	I_{OUT}	±25		mA
DC V_{CC}/ground current	I_{CC}	±50		mA
Power dissipation	P_D	180		mW
Storage temperature	T_{stg}	−65 to 150		°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.
Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: V_{CC} = 0 V

Note 3: High or low state. I_{OUT} absolute maximum rating must be observed.

Note 4: V_{OUT} < GND, V_{OUT} > V_{CC}

Operating Ranges (Note 1)

Characteristics	Symbol	Rating		Unit
Supply voltage	V_{CC}	4.5 to 5.5		V
Input voltage	V_{IN}	0 to 5.5		V
Output voltage	V_{OUT}	0 to 5.5	(Note 2)	V
		0 to V_{CC}	(Note 3)	
Operating temperature	T_{opr}	−40 to 85		°C
Input rise and fall time	dt/dV	0 to 20		ns/V

Note 1: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND.

Note 2: V_{CC} = 0 V

Note 3: High or low state

Electrical Characteristics

DC Characteristics

Characteristics	Symbol	Test Condition		V_{CC} (V)	Ta = 25°C			Ta = −40 to 85°C		Unit
					Min	Typ.	Max	Min	Max	
High-level input voltage	V_{IH}	—		4.5 to 5.5	2.0	—	—	2.0	—	V
Low-level input voltage	V_{IL}	—		4.5 to 5.5	—	—	0.8	—	0.8	V
High-level output voltage	V_{OH}	V_{IN} = V_{IH} or V_{IL}	I_{OH} = −50 μA	4.5	4.40	4.50	—	4.40	—	V
			I_{OH} = −8 mA	4.5	3.94	—	—	3.80	—	
Low-level output voltage	V_{OL}	V_{IN} = V_{IH} or V_{IL}	I_{OL} = 50 μA	4.5	—	0.0	0.1	—	0.1	V
			I_{OL} = 8 mA	4.5	—	—	0.36	—	0.44	
Input leakage current	I_{IN}	V_{IN} = 5.5 V or GND		0 to 5.5	—	—	±0.1	—	±1.0	μA
Quiescent supply current	I_{CC}	V_{IN} = V_{CC} or GND		5.5	—	—	2.0	—	20.0	μA
	I_{CCT}	Per input: V_{IN} = 3.4 V Other input: V_{CC} or GND		5.5	—	—	1.35	—	1.50	mA
Output leakage current	I_{OPD}	V_{OUT} = 5.5 V		0	—	—	0.5	—	5.0	μA

Timing Requirements (input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Test Condition		Ta = 25°C	Ta = −40 to 85°C	Unit
			V_{CC} (V)	Limit	Limit	
Minimum pulse width (CK)	$t_{w\,(L)}$ $t_{w\,(H)}$	—	5.0 ± 0.5	5.0	5.0	ns
Minimum pulse width ($\overline{CLR}$, $\overline{PR}$)	$t_{w\,(L)}$	—	5.0 ± 0.5	5.0	5.0	ns
Minimum set-up time	t_s	—	5.0 ± 0.5	5.0	5.0	ns
Minimum hold time	t_h	—	5.0 ± 0.5	0.0	0.0	ns
Minimum removal time ($\overline{CLR}$, $\overline{PR}$)	t_{rem}	—	5.0 ± 0.5	3.5	3.5	ns

AC Characteristics (input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Test Condition			Ta = 25°C			Ta = −40 to 85°C		Unit
			V_{CC} (V)	C_L (pF)	Min	Typ.	Max	Min	Max	
Propagation delay time (CK-Q, $\overline{Q}$)	t_{pLH} t_{pHL}	—	5.0 ± 0.5	15	—	5.8	7.8	1.0	9.0	ns
				50	—	6.3	8.8	1.0	10.0	
Propagation delay time ($\overline{CLR}$, $\overline{PR}$-Q, $\overline{Q}$)	t_{pLH} t_{pHL}	—	5.0 ± 0.5	15	—	7.6	10.4	1.0	12.0	ns
				50	—	8.1	11.4	1.0	13.0	
Maximum clock frequency	f_{max}	—	5.0 ± 0.5	15	100	160	—	80	—	MHz
				50	80	140	—	65	—	
Input capacitance	C_{IN}	—			—	4	10	—	10	pF
Power dissipation capacitance	C_{PD}	(Note)			—	24	—	—	—	pF

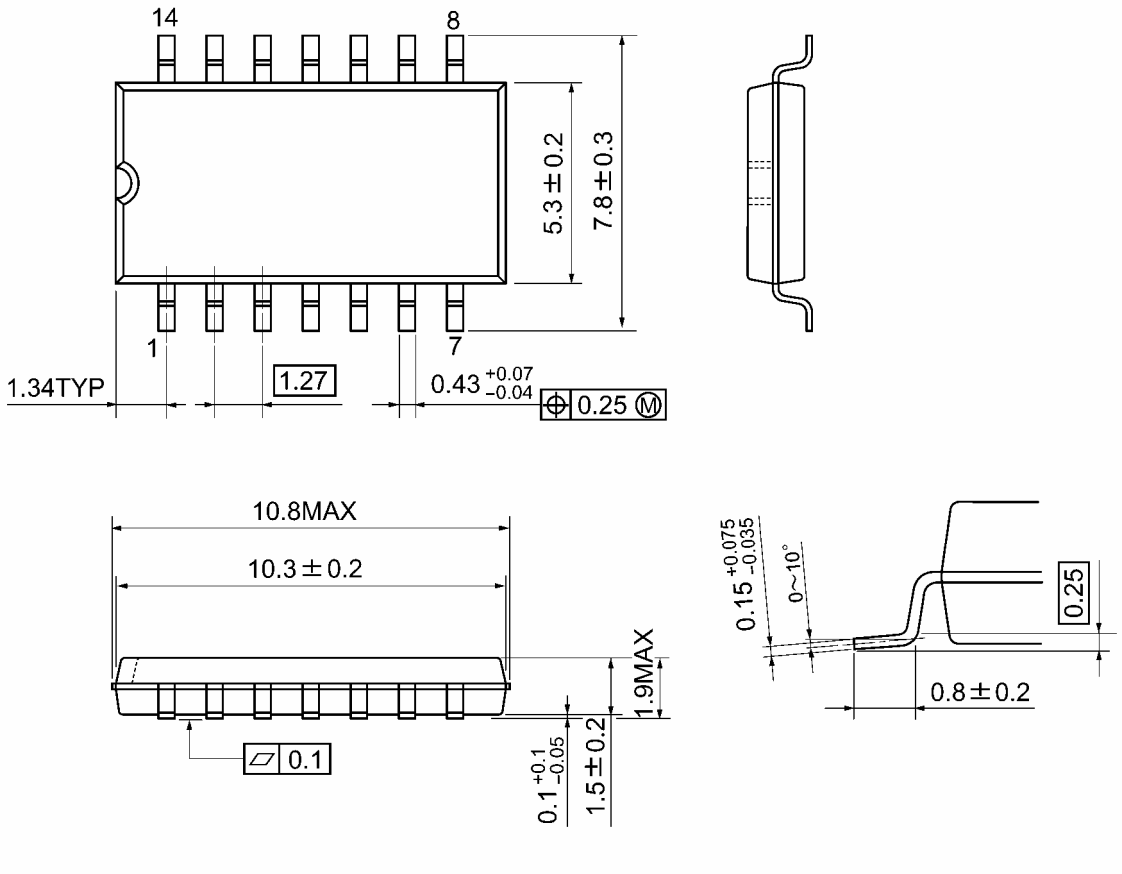
Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

$$I_{CC\,(opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/2 \text{ (per F/F)}$$

Package Dimensions

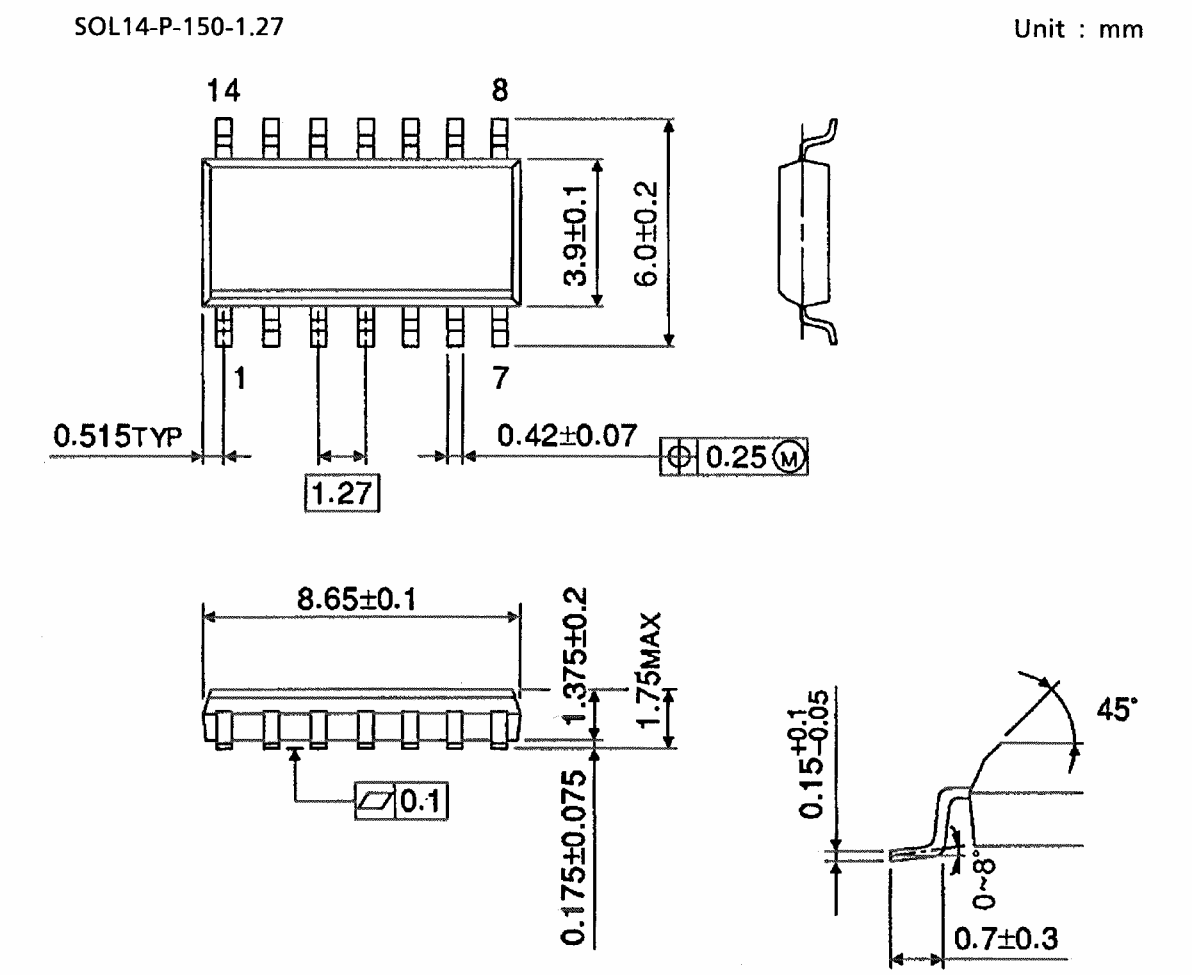
SOP14-P-300-1.27A Unit: mm



Weight: 0.18 g (typ.)

Package Dimensions (Note)

SOL14-P-150-1.27 Unit : mm

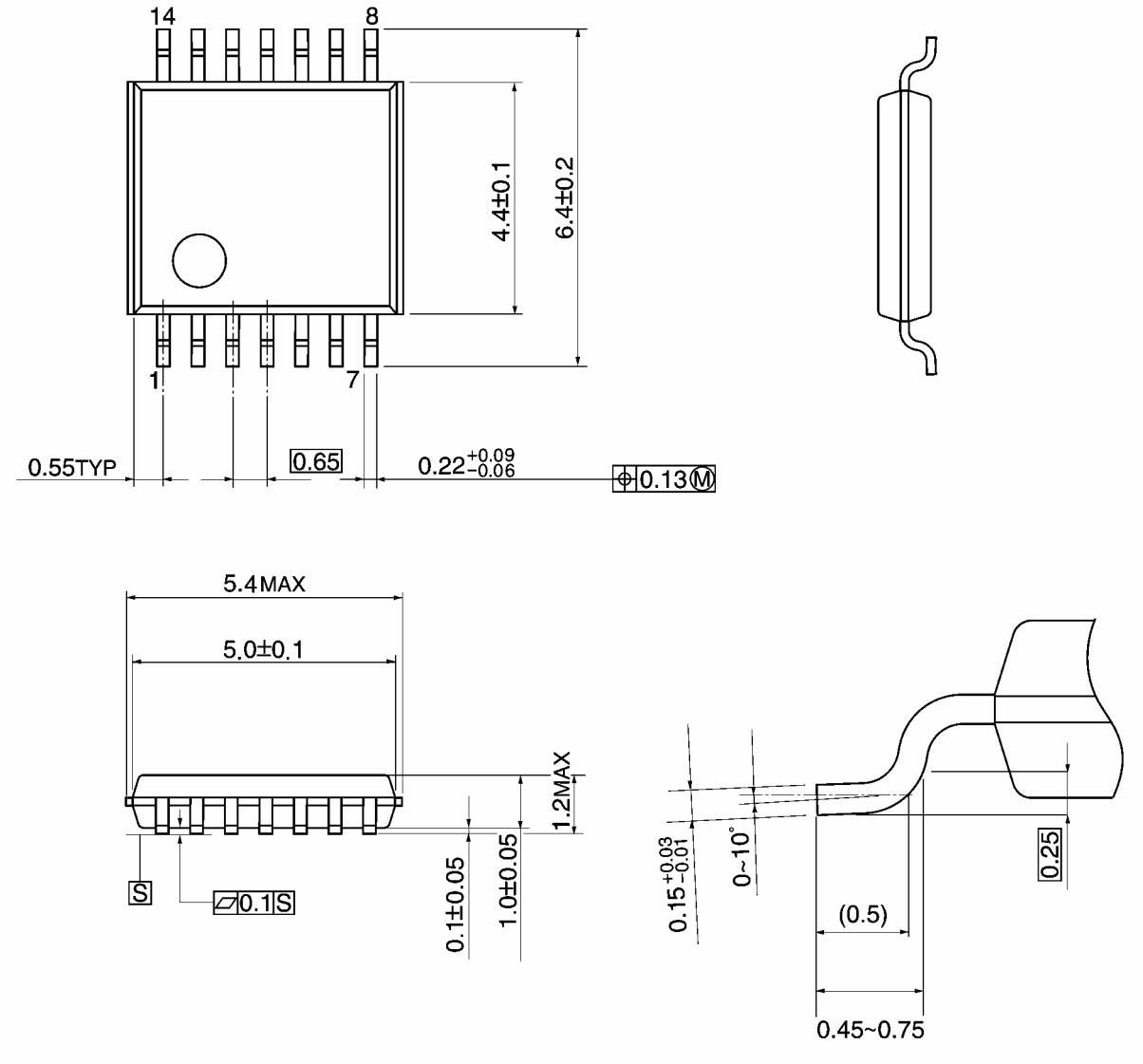


Note: This package is not available in Japan.

Weight: 0.12 g (typ.)

Package Dimensions

TSSOP14-P-0044-0.65A Unit: mm



Weight: 0.06 g (typ.)

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20070701-EN GENERAL

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